

Powered-off Protection, 1 Ω , 1.8 V to 5.5 V, SPDT Analog Switch (2:1 Multiplexer)

DESCRIPTION

The DG2012E is a high performance single-pole, double-throw (SPDT) analog switch designed for 1.8 V to 5.5 V operation with a single power rail.

Fabricated with high density CMOS technology, the device achieves low on resistance of 1 Ω at a 5 V power supply, low power consumption, and fast switching speeds.

The DG2012E can handle both analog and digital signals and permits signals with amplitudes of up to V+ to be transmitted in either direction. Its control logic inputs can go over V+ up to 5.5 V. It features break before make switching performance. Its -3 dB bandwidth is typically 160 MHz.

A powered-off protection circuit is built into the switch to prevent an abnormal current flow from COM pin to V+ during the power-down condition. Each output pin can withstand greater than 7 kV (human body model).

Operation temperature is specified from -40 $^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$.

The DG2012E is available in SC-70-6L package.

FEATURES

- Low switch on-resistance (1 Ω)
- 1.65 V to 5.5 V single supply operation
- Isolation in powered-off mode
- Control logic inputs can go over V+
- Low charge injection (5 pC)
- Low total harmonic distortion
- Break before make switching
- Latch-up performance exceeds 300 mA per JESD 78
- ESD tested
 - 7000 V human body model (JS-001)
 - 1000 V charge device model (JS-002)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?999912

Note

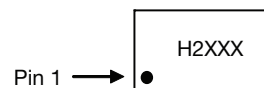
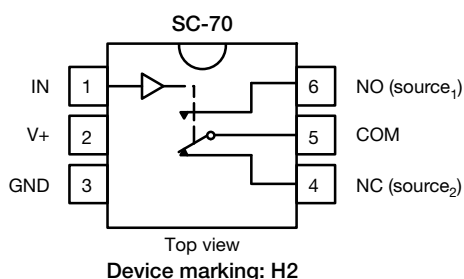
* This datasheet provides information about parts that are RoHS-compliant and / or parts that are non RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information / tables in this datasheet for details



APPLICATIONS

- Smartphones and tablets
- Consumer and computing
- Portable instrumentation
- Medical equipment

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device marking: H2XXX
XXX = date / lot traceability code

TRUTH TABLE		
LOGIC	NC	NO
0	On	Off
1	Off	On

ORDERING INFORMATION		
TEMP. RANGE	PACKAGE	PART NUMBER
-40 $^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$	SC-70-6	DG2012EDL-T1-GE3

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER		LIMIT	UNIT
V+, COM, NC, NO, IN reference to GND		-0.3 to 6	V
Continuous current (NO, NC, and COM pins)		± 100	mA
Peak current (pulsed at 1 ms, 10 % duty cycle)		± 300	
Storage temperature (D suffix)		-65 to +150	°C
Power dissipation (packages) ^a	6-pin SO-70 ^b	250	mW
ESD / HBM	JS-001	7000	V
ESD / CDM	JS-002	1000	
Latch up	Per JEDEC78 with 1.5 x voltage clamp	300	mA

Notes

a. All leads welded or soldered to PC board

b. Derate 3.1 mW/°C above 70 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

SPECIFICATIONS (V+ = 5 V)

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 5 V, ± 10 %, VIN = 0.8 V or 2.4 V ^e	TEMP. ^a	LIMITS -40 °C to +85 °C			UNIT
				MIN. ^b	TYP. ^c	MAX. ^b	
Analog Switch							
Analog signal range ^d	VNO, VNC VCOM		Full	0	-	V+	V
On-resistance	RON	V+ = 4.5 V, VCOM = 0.5 V / 2.5 V, INO, INC = 10 mA	Room Full ^d	- -	1 -	1.6 2	Ω
RON flatness ^d	RON flatness	V+ = 4.5 V, VCOM = 0 V to V+, INO, INC = 10 mA	Room	-	0.2	0.5	
RON match ^d	ΔRON		Room	-	-	0.3	
Switch off leakage current ^f	INO(off) INC(off)	V+ = 5 V VNO, VNC = 0.5 V / 4.5 V, VCOM = 4.5 V / 0.5 V	Room	-5	-	5	nA
			Full	-20	-	20	
	ICOM(off)		Room	-5	-	5	
			Full ^d	-20	-	20	
Channel-on leakage current ^f	ICOM(on)	Room	-5	-	5		
		Full ^d	-20	-	20		
Power down leakage	ICOM(PD)	V+ = 0 V, VCOM = 4.5 V, VIN = GND	Full ^d	-1	-	1	μA
Digital Control							
Input high voltage	VINH		Full	2.4	-	-	V
Input low voltage	VINL		Full	-	-	0.8	
Input capacitance ^d	CIN		Full	-	3	-	pF
Input current ^f	IINL or IINH	VIN = 0 V or V+	Full	-1	-	1	μA
Dynamic Characteristics							
Turn-on time ^d	tON	VNO or VNC = 3 V, RL = 300 Ω, CL = 35 pF	Room	-	15	32	ns
			Full ^d	-	-	35	
Turn-off time ^d	tOFF		Room	-	7	28	
			Full ^d	-	-	30	
Break-before-make time ^d	tD		Room	1	5	-	
Charge injection ^d	QINJ	CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω	Room	-	8	-	pC
Off-isolation ^d	OIRR	RL = 50 Ω, CL = 5 pF, f = 1 MHz	Room	-	-63	-	dB
Crosstalk ^d	XTALK		Room	-	-63	-	
NO, NC off capacitance ^d	CNO(off) CNC(off)	VIN = 0 V or V+, f = 1 MHz	Room	-	16	-	pF
Channel-on capacitance ^d	CON		Room	-	52	-	
Power Supply							
Power supply current	I+	VIN = 0 V or V+	Full	-	0.0003	1	μA



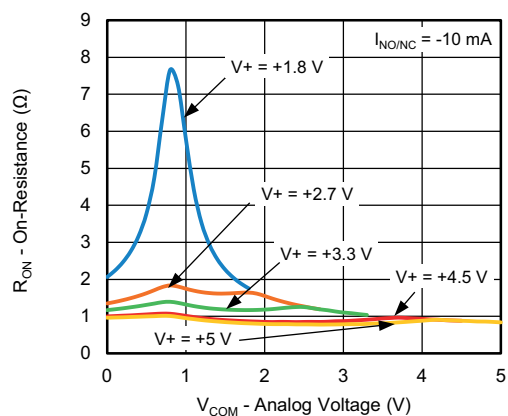
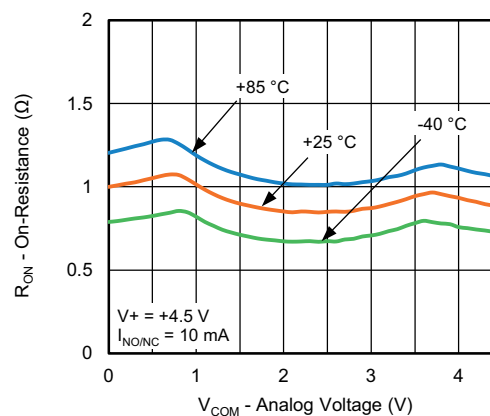
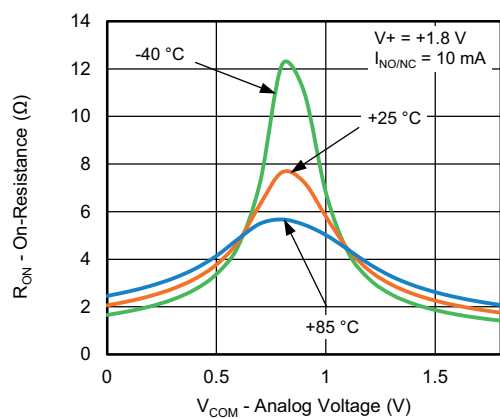
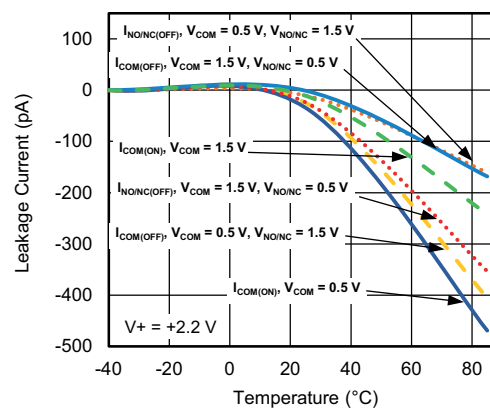
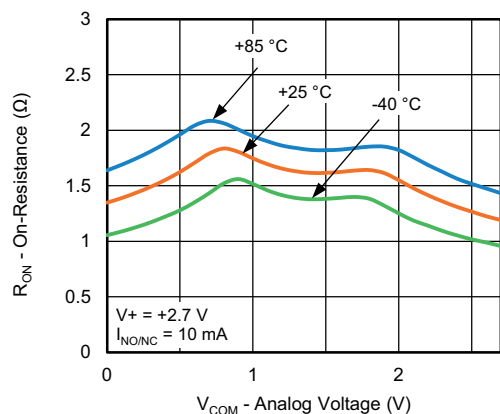
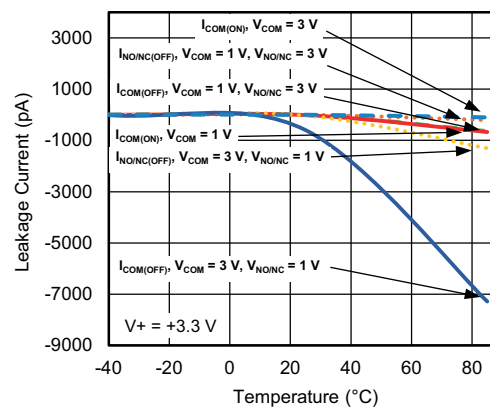
SPECIFICATIONS (V+ = 3 V)							
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 3 V, ± 10 %, VIN = 0.4 V or 1.4 V e	TEMP. a	LIMITS -40 °C to 85 °C			UNIT
				MIN. b	TYP. c	MAX. b	
Analog Switch							
Analog signal range d	VNO, VNC VCOM		Full	0	-	V+	V
On-resistance	RON	V+ = 2.7 V, VCOM = 0.2 V / 1.5 V, INO INC = 10 mA	Room Full d	- -	1.4 -	2.5 3	Ω
RON flatness d	RON flatness	V+ = 2.7 V, VCOM = 0 V to V+, INO, INC = 10 mA	Room	-	0.6	0.9	
RON match d	ΔRON		Room	-	-	0.3	
Switch off leakage current f	INO(off) INC(off)	V+ = 3.3 V VNO, VNC = 1 V / 3 V, VCOM = 3 V / 1 V	Room	-5	-	5	nA
	ICOM(off)		Full	-15	-	15	
			Room	-5	-	5	
			Full d	-15	-	15	
Channel-on leakage current f	ICOM(on)	V+ = 3.3 V, VNO, VNC = VCOM = 1 V / 3 V	Room	-5	-	5	
			Full d	-15	-	15	
Digital Control							
Input high voltage	VINH		Full	1.4	-	-	V
Input low voltage	VINL		Full	-	-	0.4	
Input capacitance d	CIN		Full	-	3	-	pF
Input current f	INL or INH	VIN = 0 V or V+	Full	-1	-	1	μA
Dynamic Characteristics							
Turn-on time d	tON	VNO or VNC = 2 V, RL = 300 Ω, CL = 35 pF	Room	-	21	42	ns
			Full d	-	-	47	
Turn-off time d	tOFF		Room	-	16	32	
			Full d	-	-	35	
Break-before-make time d	td		Room	1	7	-	
Charge injection d	QINJ	CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω	Room	-	6	-	pC
Off-isolation d	OIRR	RL = 50 Ω, CL = 5 pF, f = 1 MHz	Room	-	-63	-	dB
Crosstalk d	XTALK		Room	-	-63	-	
Bandwidth d	BW		Room	-	160	-	MHz
NO, NC off capacitance d	CNO(off) CNC(off)	VIN = 0 V or V+, f = 1 MHz	Room	-	16	-	pF
Channel-on capacitance d	CON		Room	-	52	-	
Power Supply							
Power supply current	I+	VIN = 0 V or V+	Full	-	0.00002	1	μA

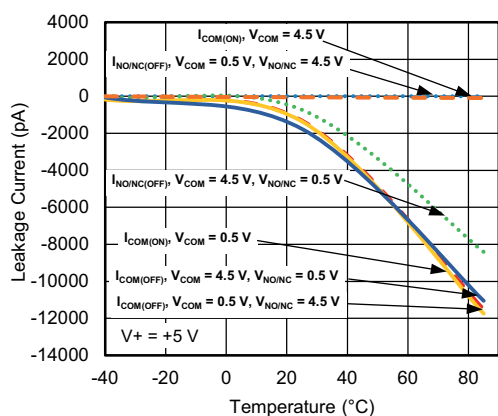
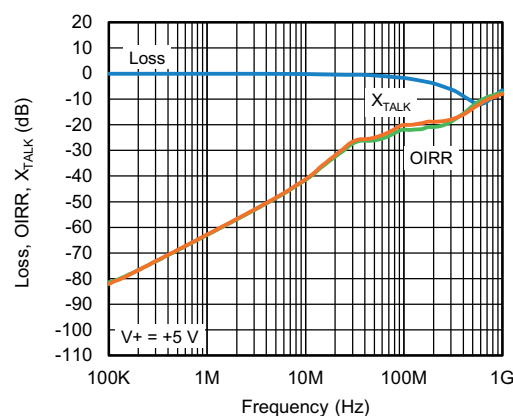
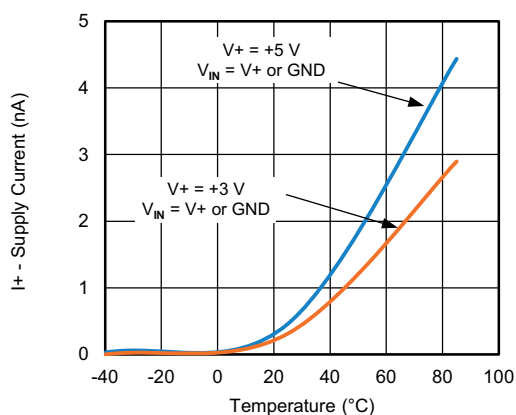
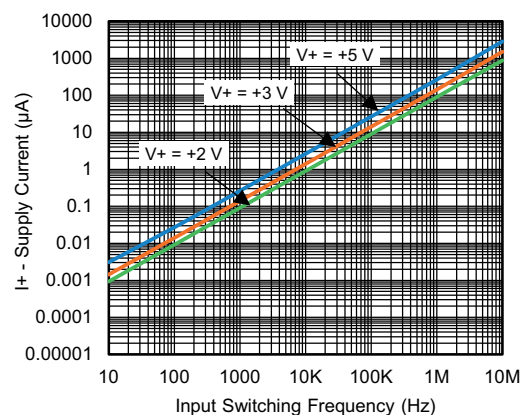
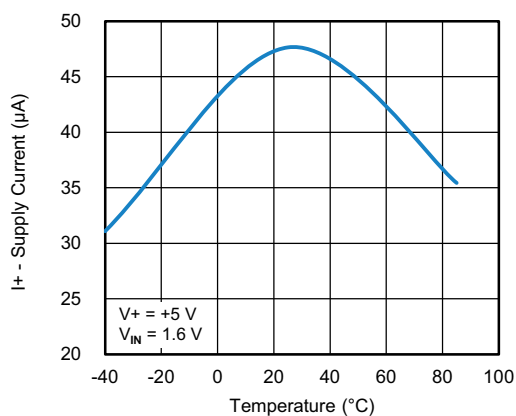
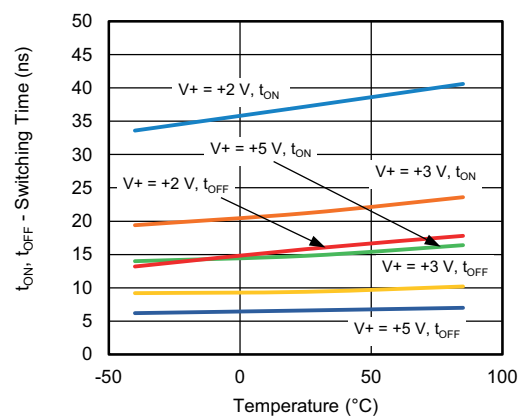


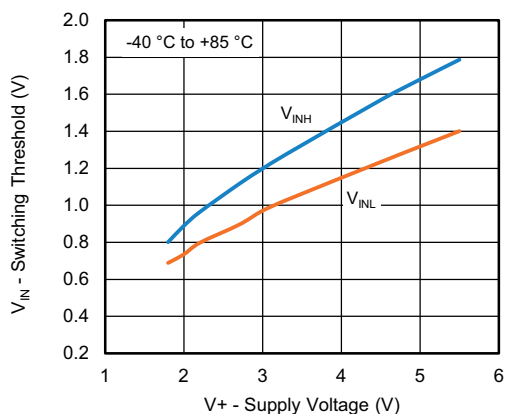
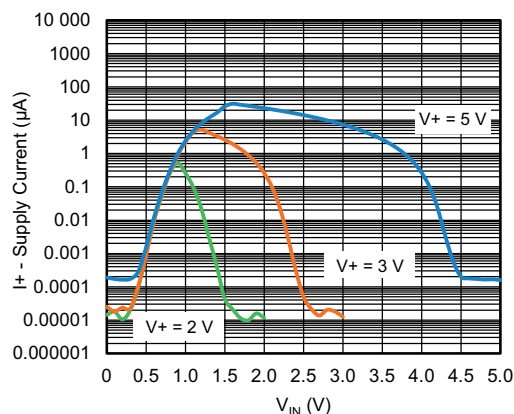
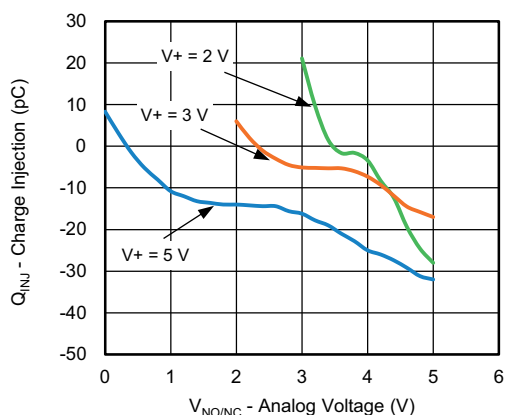
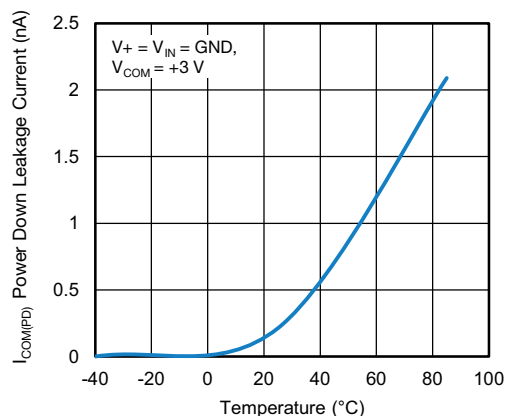
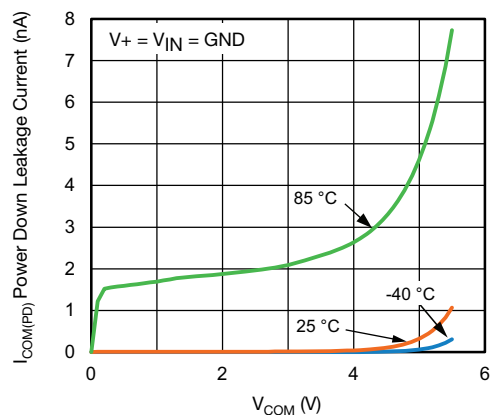
SPECIFICATIONS (V+ = 2 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 2 V, ± 10 %, VIN = 0.4 V or 1.6 V e	TEMP. a	LIMITS -40 °C to +85 °C			UNIT		
				MIN. b	TYP. c	MAX. b			
Analog Switch									
Analog signal range d	VNO, VNC, VCOM		Full	0	-	V+	V		
On-resistance	RON	V+ = 1.8 V, VCOM = 0.2 V / 0.9 V INO, INC = 10 mA	Room Full d	- -	5 -	10 15	Ω		
RON flatness d	RON flatness	V+ = 1.8 V, VCOM = 0 V to V+, INO, INC = 10 mA	Room	-	6	9			
RON match d	ΔRON		Room	-	-	0.3			
Switch off leakage current f	INO(off) INC(off)	V+ = 2.2 V VNO, VNC = 0.5 V / 1.5 V, VCOM = 1.5 V / 0.5 V	Room Full	-0.5 -5	- -	0.5 5	nA		
	ICOM(off)		Room Full d	-0.5 -5	- -	0.5 5			
			Channel-on leakage current f	ICOM(on)	V+ = 2.2 V, VNO, VNC = VCOM = 0.5 V / 1.5 V	Room Full d		-0.5 -5	- -
	Digital Control								
Input high voltage	VINH		Full	1.6	-	-	V		
Input low voltage	VINL		Full	-	-	0.4			
Input capacitance d	CIN		Full	-	3	-	pF		
Input current f	IINL or IINH	VIN = 0 V or V+	Full	-1	-	1	μA		
Dynamic Characteristics									
Turn-on time d	tON	VNO or VNC = 1.5 V, RL = 300 Ω, CL = 35 pF	Room Full d	- -	37 -	57 60	ns		
Turn-off time d	tOFF		Room Full d	- -	26 -	44 45			
			Room	1	17	-			
Break-before-make time d	td			Room	1	17		-	
Charge injection d	QINJ	CL = 1 nF, VGEN = 0 V, RGEN = 0 Ω	Room	-	21	-	pC		
Off-isolation d	OIRR	RL = 50 Ω, CL = 5 pF, f = 1 MHz	Room	-	-63	-	dB		
Crosstalk d	XTALK		Room	-	-63	-			
NO, NC off capacitance d	CNO(off) CNC(off)	VIN = 0 V or V+, f = 1 MHz	Room	-	16	-	pF		
Channel-on capacitance d	CON		Room	-	51	-			
Power Supply									
Power supply current	I+	VIN = 0 V or V+	Full	-	0.00001	1	μA		

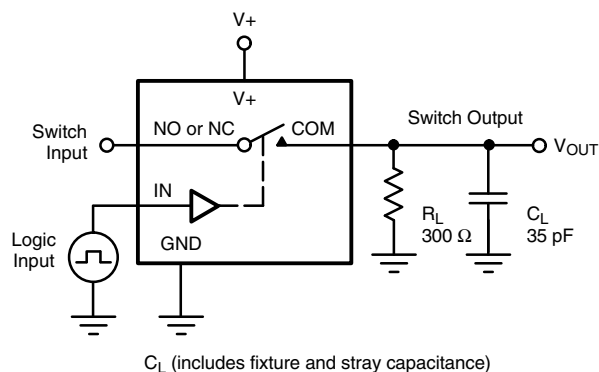
Notes

- a. Room = 25 °C, full = as determined by the operating suffix
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
c. Typical values are for design aid only, not guaranteed nor subject to production testing
d. Guarantee by design, nor subjected to production test
e. V_{IN} = input voltage to perform proper function
f. Guaranteed by 5 V leakage testing, not production tested

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

 R_{ON} vs. V_{COM} and Supply Voltage

 R_{ON} vs. V_{COM} and Temperature

 R_{ON} vs. V_{COM} and Temperature

Leakage Current vs. Temperature

 R_{ON} vs. V_{COM} and Temperature

Leakage Current vs. Temperature

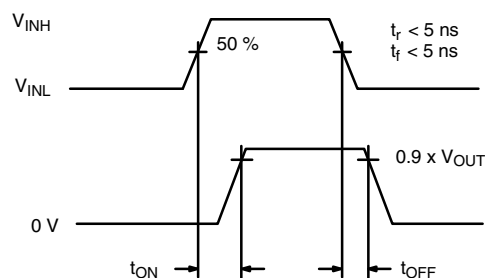
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Leakage Current vs. Temperature

Insertion Loss, Off-Isolation Crosstalk vs. Frequency

Supply Current vs. Temperature

Supply Current vs. Input Switching Frequency

Supply Current vs. Temperature

Switching Time vs. Temperature and Supply Voltage

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Switching Threshold vs. Supply Voltage

Supply Current vs. Enable Input Voltage

Charge Injection vs. Analog Voltage

Power Down Leakage Current vs. Temperature

Power Down Leakage Current vs. V_{COM}

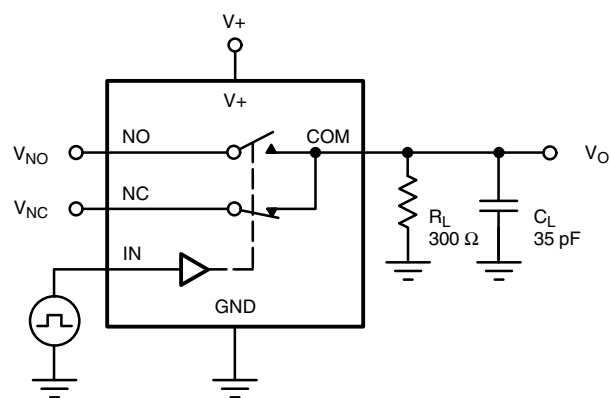
TEST CIRCUITS

 C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left(\frac{R_L}{R_L + R_{ON}} \right)$$

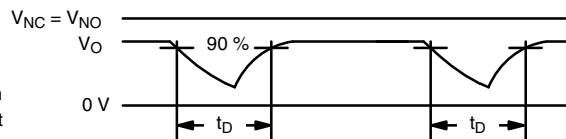
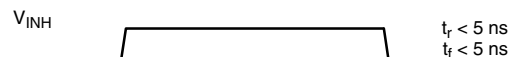
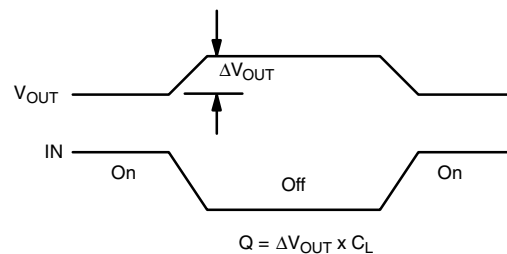
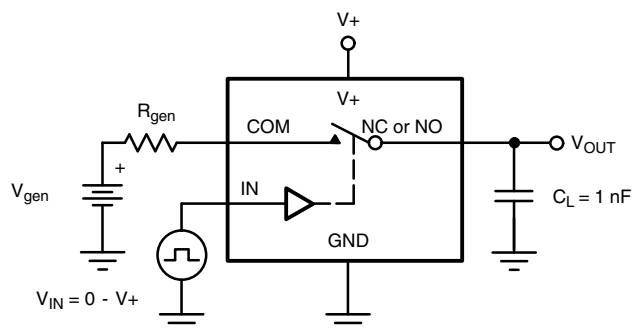
Logic Input



Logic "1" = Switch On
Logic input waveforms inverted for switches that have the opposite logic sense.

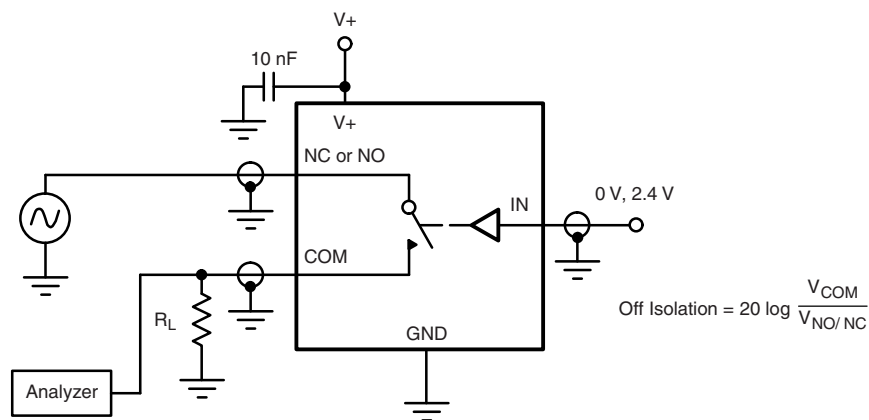
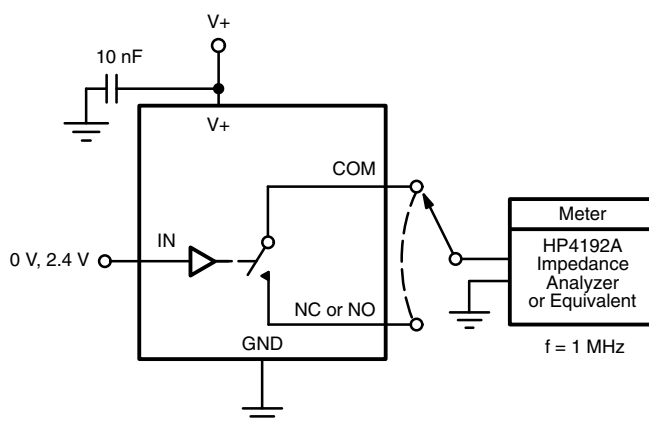
Fig. 1 - Switching Time

 C_L (includes fixture and stray capacitance)

Logic Input


Fig. 2 - Break-Before-Make Interval


IN depends on switch configuration: input polarity determined by sense of switch.

Fig. 3 - Charge Injection

TEST CIRCUITS

Fig. 4 - Off-Isolation

Fig. 5 - Channel Off / On Capacitance

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